

General Description

This product family offers state of the art performance. It is designed for high frequency applications where high efficiency and high reliability are required.

Features

- Low conduction loss due to low V_F
- Extremely low switching loss by tiny Qc
- Highly rugged due to better surge current
- Industrial standard quality and reliability

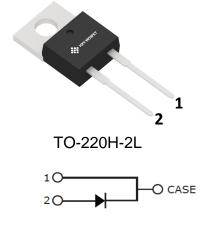
Applications

- UPS
- Power Inverter
- High performance SMPS
- Power factor correction





Part Number	Package	Marking
SCS105KGC	TO-220H-2L	S105CBK





Maximum Ratings (Tc = 25 °C unless otherwise specifed)

Symbol	Parameter	Value	Unit	Test Conditions
V_{RRM}	Repetitive Peak Reverse Voltage	1200	V	
V _{RSM}	Surge Peak Reverse Voltage	1200	V	
V _R	DC Blocking Voltage	1200	V	
I _F	Continuous Forward Current	18 9 5	А	T _c =25°C T _c =135°C T _c =153°C
I _{FRM}	Repetitive Peak Forward Surge Current	31 23	А	T _c =25°C, t _p = 10 ms, Half Sine Wave T _c =110°C, t _p =10 ms, Half Sine Wave
I _{FSM}	Non-Repetitive Peak Forward Surge Current	45 35	А	T_c =25°C, t_p = 10 ms, Half Sine Wave T_c =110°C, t_p =10 ms, Half Sine Wave
∫i²dt	i ² dt value	10 6	A ² s	T_C = 25°C, t_p =10ms,Half Sine Pulse T_C = 110°C, t_p =10ms,Half Sine Pulse
P _{tot}	Power Dissipation	97 42	W	T _c =25°C T _c =110°C
T_{J} , T_{stg}	Operating Junction and Storage Temperature	-55 to +175	°C	



Electrical Characteristics

Parameter	Symbol	Value		Unit	Test Condition		
Parameter	Syllibol	min.	typ.	max.	Oilit	rest Condition	
						I _F =5A	
Forward Voltage	V_{F}	-	1.4	1.7	V	T _j =25°C	
		-	2.0			T _j =175°C	
						V _R =1200V	
Reverse Current	I _R	-	-	100	μΑ	T _j =25°C	
		-	-	200		T _j =175°C	
						V _R =800V,T _j =25℃	
Total Capacitive Charge	Q _C	1	24	-	nC	$Q_C = \int_0^{V_R} C(V) dV$	
						T _j =25℃, f=1MHz	
Total Capacitance	С	-	336	-	pF	V _R =0V	
		-	23	-		V _R =400V	
		-	18	-		V _R =800V	

Thermal Characteristics

Symbol	Parameter	Тур.	Unit
$R_{_{ ext{ hetaJC}}}$	Thermal Resistance from Junction to Case	1.55	°C/W

Characteristics Curve

Fig 1: Forward Characteristics

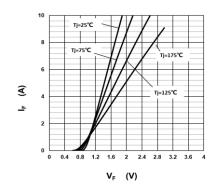


Fig 2: Reverse Characteristics

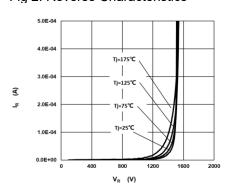


Fig 3: Current Derating

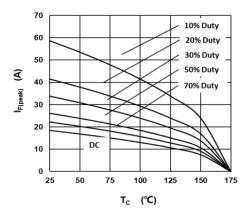


Fig 5: Capacitance vs. Reverse Voltage

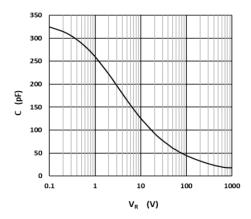


Fig 7: Typical Capacitance Stored Energy

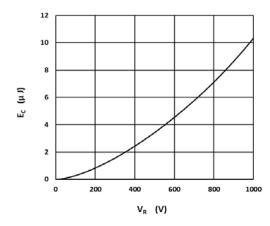


Fig 4: Power Derating

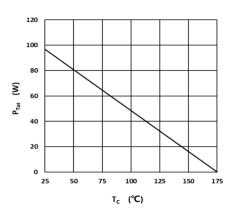


Fig 6: Reverse Charge vs. Reverse Voltage

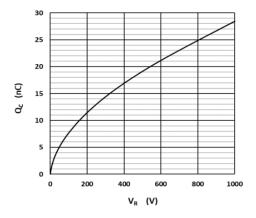
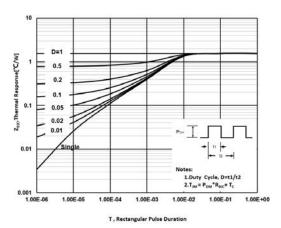
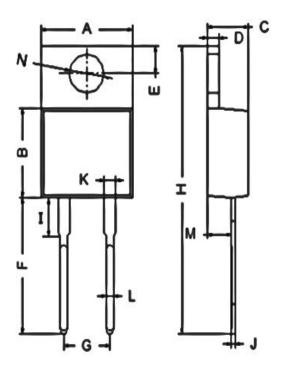


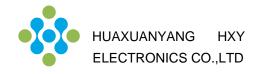
Fig 8: Transient Thermal Impandance



Package Information TO-220H-2L



POS	Millimeters		
PU3	Min.	Max.	
Α	9.80	10.50	
В	8.60	9.20	
С	4.37	4.77	
D	1.07	1.47	
Е	2.40	3.00	
F	13.14	14.20	
G	4.90	5.24	
Н	28.00	29.20	
I	3.50	4.00	
J	0.28	0.50	
K	1.20	1.50	
L	0.70	0.90	
М	2.40	2.90	
N	3.70	4.00	



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